Thyristor Semiconductor Device - Page 1 of 1



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Met	al
	erall Length:
	50 inches
Ter	minal Length:
	00 inches
Ove	erall Diameter:
0.37	70 inches
Inte	rnal Configuration:
Jun	ction contact
Μοι	unting Method:
Terr	minal
Ter	minal Circle Diameter:
0.20	00 inches
Fea	tures Provided:
Her	metically sealed case
Sen	niconductor Material:
Silic	zon
Vol	tage Rating In Volts Per Characteristic:
50.0	) breakover voltage, dc
Cur	rent Rating Per Characteristic:
1.30	) amperes source cutoff current
Max	kimum Operating Tempurature Per Measurement Point:
150	.0 degrees celsius junction
Spe	cial Features:
Jun	ction pattern arrangement: pnpn
Ter	minal Type And Quantity:
3 ur	ninsulated wire lead
Spe	cification Data:
801	31-release4400 professional/industrial association specification
She	elf Life:
N/a	
Uni	t Of Measure:
Den	nilitarization:
No	
Fiig	: